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April 1st, 2010 Renesas Electronics Corporation

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HAF1008(L), HAF1008(S)

Silicon P Channel MOS FET Series Power Switching

REJ03G0027-0100Z Rev.1.00 May.13.2003

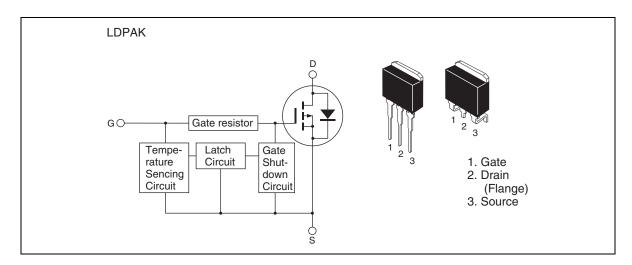
Description

This FET has the over temperature shut—down capability sensing to the junction temperature. This FET has the built—in over temperature shut—down circuit in the gate area. And this circuit operation to shut—down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

Features

- Logic level operation (-4 to -6 V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Latch type shut–down operation (Need 0 voltage recovery)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	-60	V
Gate to source voltage	V _{GSS}	–16	V
Gate to source voltage	V_{GSS}	2.5	V
Drain current	I_D	-20	A
Drain peak current	I _D (pulse) Note1	–40	A
Body-drain diode reverse drain current	I _{DR}	-20	Α
Channel dissipation	Pch ^{Note2}	50	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1 %

2. Value at Tc = 25°C

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V_{IH}	-3.5	_	_	V	
	V _{IL}	_	_	-1.2	V	
Input current (Gate non shut down)	I _{IH1}	_	_	-100	μΑ	Vi = -8 V, V _{DS} = 0
	I _{IH2}	_	_	-50	μΑ	$Vi = -3.5 V, V_{DS} = 0$
	I _{IL}	_	_	– 1	μΑ	$Vi = -1.2 V, V_{DS} = 0$
Input current (Gate shut down)	I _{IH(sd)1}	_	-0.8	_	mA	$Vi = -8 V, V_{DS} = 0$
	I _{IH(sd)2}	_	-0.35	_	mA	$Vi = -3.5 V, V_{DS} = 0$
Shut down temperature	Tsd	_	175	_	°C	Channel temperature
Gate operation voltage	Vop	-3.5	_	-12	V	

Electrical Characteristics

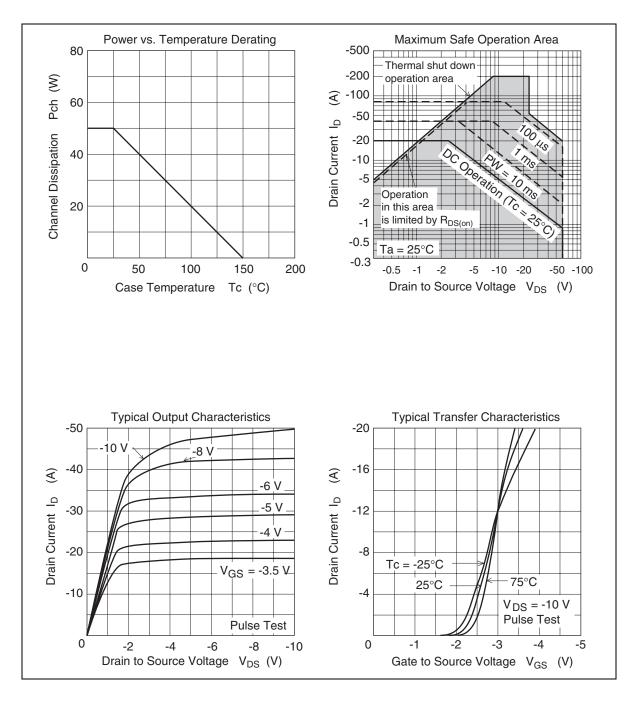
 $(Ta = 25^{\circ}C)$

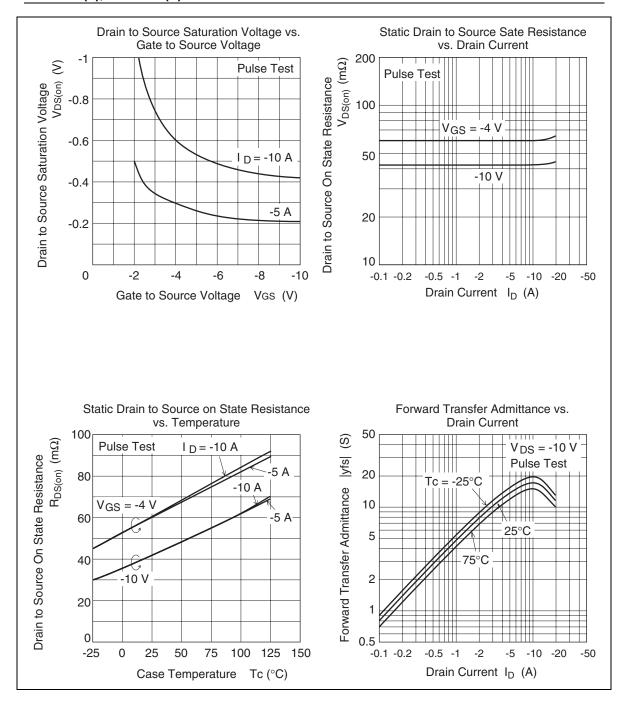
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	- 7	_	_	Α	$V_{GS} = -3.5 \text{ V}, V_{DS} = -2 \text{ V}$
Drain current	I _{D2}	_	_	-10	mA	V _{GS} = -1.2 V, V _{DS} = -2 V
Drain to source breakdown voltage	V _{(BR)DSS}	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR)GSS}	– 16	_	_	V	$I_G = -800 \ \mu A, \ V_{DS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	2.5	_	_	V	I _G = 100 μA, V _{DS} = 0
Gate to source leak current	I _{GSS1}	_	_	-100	μA	V _{GS} = -8 V, V _{DS} = 0
	I _{GSS2}	_	_	-50	μA	V _{GS} = -3.5 V, V _{DS} = 0
	I _{GSS3}	_	_	– 1	μΑ	V _{GS} = -1.2 V, V _{DS} = 0
	I _{GSS4}	_	_	100	μA	V _{GS} = 2.4 V, V _{DS} = 0
Input current (shut down)	I _{GS(OP)1}	_	-0.8	_	mA	V _{GS} = -8 V, V _{DS} = 0
	I _{GS(OP)2}	_	-0.35	_	mA	V _{GS} = -3.5 V, V _{DS} = 0
Zero gate voltage drain current	I _{DSS}	_	_	-10	μΑ	V _{DS} = -60 V, V _{GS} = 0
Gate to source cutoff voltage	$V_{GS(off)}$	-1.1	_	-2.15	V	V _{DS} = -10 V, I _D = -1 mA
Forward transfer admittance	y _{fs}	10	18.5	_	S	$I_D = -10 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note3}}$
Static drain to source on state resistance	R _{DS(on)}	_	60	80	$m\Omega$	$I_D = -10 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note3}}$
	R _{DS(on)}	_	42	54	mΩ	$I_D = -10 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note3}}$
Output capacitance	Coss	_	865	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$
Turn-on delay time	td(on)	_	5.7	_	μs	V_{GS} = -10 V, I_D = -10 A, R_L = 3 Ω
Rise time	tr	_	26	_	μs	
Turn-off delay time	td(off)	_	6.5	_	μs	
Fall time	tf	_	9	_	μs	
Body-drain diode forward voltage	V_{DF}	_	-0.9	_	V	$I_F = -20 \text{ A}, V_{GS} = 0$
Body–drain diode reverse recovery time	trr	_	100	_	ns	$I_F = -20 \text{ A}, V_{GS} = 0$ diF/dt = 50A/ μ s
Over load shut down	t _{os1}	_	1.84	_	ms	V _{GS} = -5 V, V _{DD} = -16 V
operation time Note4	t _{os2}	_	1	_	ms	$V_{GS} = -5 \text{ V}, V_{DD} = -24 \text{ V}$

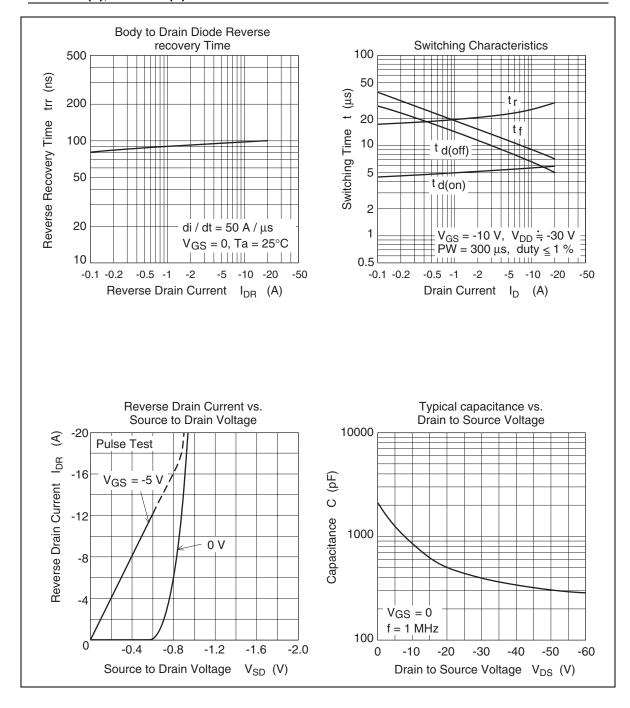
Notes: 3. Pulse test

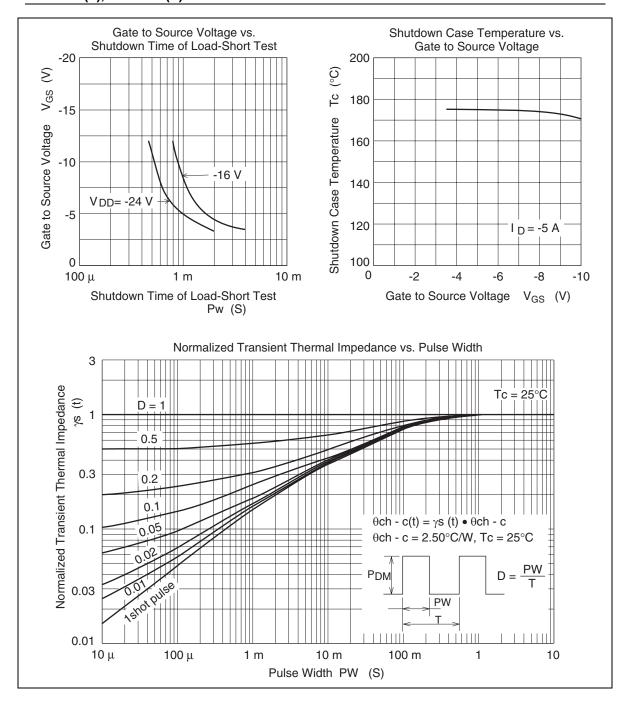
4. Include the time shift based on increasing of channel temperature when operate under over load condition.

Main Characteristics

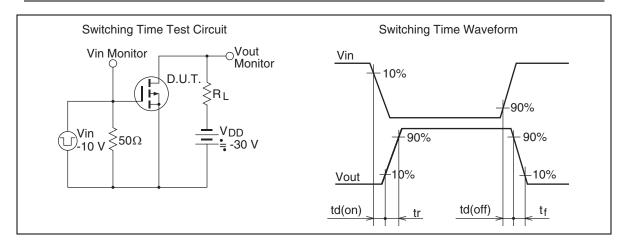




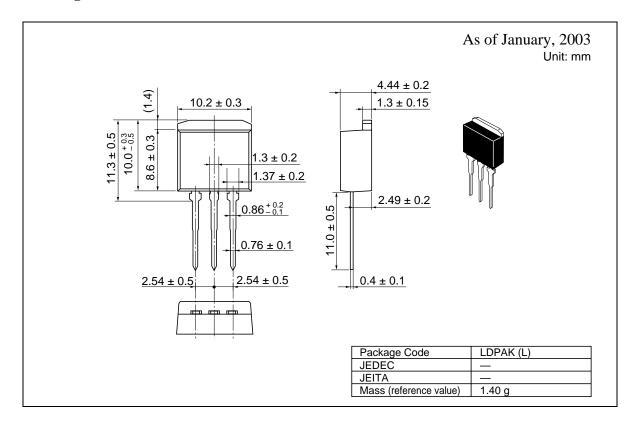


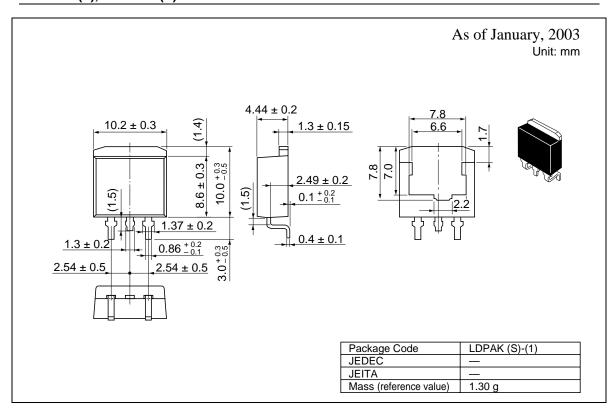


HAF1008(L), HAF1008(S)



Package Dimensions





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